

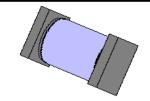
## 1N6661US thru 1N6663US

# VOIDLESS-HERMETICALLY-SEALED STANDARD RECOVERY GLASS RECTIFIERS

### **DESCRIPTION**

These "standard recovery" rectifier diodes are military qualified to MIL-PRF-19500/587 and is ideal for high-reliability applications where a failure cannot be tolerated. They have a 500 mA rating with working peak reverse voltages from 225 to 600 volts and are hermetically sealed with void-less-glass construction using an internal "Category I" metallurgical bond. The axial-leaded package configurations are also available by deleting the "US" suffix (see separate data sheet for 1N6661 to 1N6663). Microsemi also offers numerous other rectifier products to meet higher and lower current ratings with various recovery time speed requirements including Fast and Ultrafast device types in both through-hole and surface mount packages.

# **APPEARANCE**



Package "A" or D-5A

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

#### **FEATURES**

- Popular JEDEC registered 1N6661 thru 1N6663 series
- Voidless hermetically sealed glass package
- Triple-Layer Passivation
- Internal "Category I" Metallurgical bonds
- Working Peak Reverse Voltage 225 to 600 Volts.
- JAN, JANTX, and JANTXV available per MIL-PRF-19500/587
- Axial-leaded equivalents also available without the "US" suffix (see 1N6661 thru 1N6663)

#### **MAXIMUM RATINGS**

- Junction & Storage Temperature: -65°C to +175°C
- Thermal Resistance: 35°C/W junction to end cap
- Average Rectified Forward Current (I<sub>O</sub>): 0.5 Amps @  $T_{EC} = 110^{\circ}C$  and 0.150 Amps at  $T_{EC} = 150^{\circ}C$
- Forward Surge Current: 5 Amps @ 8.3 ms half-sine
- Solder Temperatures: 260°C for 10 s (maximum)

#### **APPLICATIONS / BENEFITS**

- Standard recovery 0.5 Amp rectifiers 225 to 600 V
- Military and other high-reliability applications
- General rectifier applications including bridges, halfbridges, catch diodes, etc.
- Forward surge current capability
- Extremely robust construction
- Low thermal resistance in small MELF package
- Inherently radiation hard as described in Microsemi MicroNote 050

#### **MECHANICAL AND PACKAGING**

- CASE: Hermetically sealed void-less hard glass with Tungsten slugs
- TERMINATIONS: End caps are copper with Tin/Lead (Sn/Pb) finish
- MARKING: Body paint
- POLARITY: Cathode band
- TAPE & REEL option: Standard per EIA-481-B
- WEIGHT: 84 mg (approx)
- See package dimensions on last page

#### **ELECTRICAL CHARACTERISTICS** MINIMUM WORKING **AVERAGE MAXIMUM MAXIMUM** PEAK **BREAKDOWN RECTIFIED FORWARD MAXIMUM REVERSE** SURGE CURRENT **REVERSE** CURRENT VOLTAGE **VOLTAGE CURRENT TYPE VOLTAGE** (NOTE 2) (NOTE 1) V<sub>F</sub> @ 0.4 A V<sub>BR</sub> @ 100μA **V<sub>RWM</sub>** (PULSED) I<sub>R</sub> @ V<sub>RWM</sub> I<sub>FSM</sub> **AMPS VOLTS** VOLTS VOLTS **AMPS** 150°C 25°C 150°C 25°C 1N6661US 225 270 300 0.5 0.15 1.0 0.05 5 1N6662US 400 480 0.5 300 5 0.15 1.0 0.05 1N6663US 600 720 0.5 1.0 0.05 300 5 0.15

**NOTE 1:** T<sub>A</sub> = 25°C, 10 surges of 8.3 ms @ 1 minute intervals

NOTE 2: Linearly derate at 8.75 mA/°C between T<sub>EC</sub> = 110°C to 150°C and 6.0 mA/°C between T<sub>EC</sub> = 150°C to 175°C

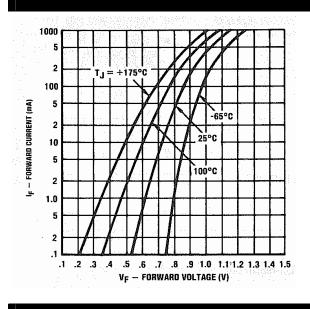


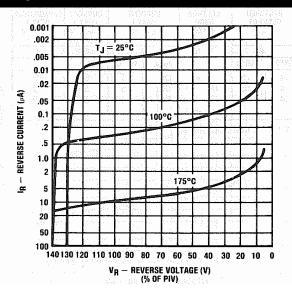
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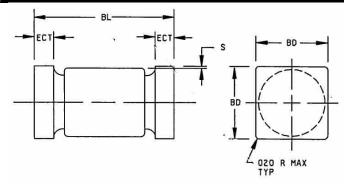
SYMBOLS & DEFINITIONS				
chibit at a specified current.				
be applied over the operating temperature range.				
will exhibit at a specified current.				
ow at the specified voltage and temperature.				

## **GRAPHS**



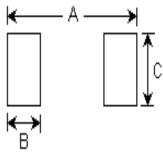


## **PACKAGE DIMENSIONS**



NOTE: This Package Outline has also previously been identified as "D-5A"

	INCHES		mm	
	MIN	MAX	MIN	MAX
BD	.097	.103	2.46	2.62
BL	.185	.200	4.70	5.08
ECT	.019	.028	0.48	0.71
S	.003		0.08	



## **PAD LAYOUT**

	INCHES	mm
Α	0.246	6.25
В	0.067	1.70
С	0.105	2.67

Note: If mounting requires adhesive separate from the solder, an additional 0.060 inch diameter contact may be placed in the center between the pads as an optional spot for cement.